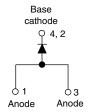


Vishay Semiconductors

# High Performance Schottky Rectifier, 3.5 A





8 mJ

**D-PAK (TO-252AA)** 

 $\mathsf{E}_{\mathsf{AS}}$ 

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I <sub>F(AV)</sub>	3.5 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub>	24 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			

#### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- $\bullet$  Meets MSL level 1, per J-STD-020, LF maximum peak of 260  $^{\circ}\text{C}$
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

The VS-30WQ04FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	3.5	Α		
V <sub>RRM</sub>		40	V		
I <sub>FSM</sub>	$t_p = 5 \mu s sine$	500	Α		
V <sub>F</sub>	3 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.49	V		
T <sub>J</sub>		-40 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-30WQ04FN-M3	UNITS	
Maximum DC reverse voltage	$V_R$	40	V	
Maximum working peak reverse voltage	$V_{RWM}$	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 135 °C	, rectangular waveform	3.5	
Maximum peak one cycle non-repetitive surge current. See fig. 7	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	500	Α
		10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	80	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 16 mH		8.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V (1)	3 A	T <sub>J</sub> = 25 °C	0.53	V
		6 A		0.67	
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	3 A	T 105 °C	0.49	
		6 A	T <sub>J</sub> = 125 °C	0.62	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V DetectV	2	A
See fig. 2	IRM (")	$T_{\rm J}$ = 125 °C $V_{\rm R}$ = Rated $V_{\rm R}$		24	– mA
Threshold voltage	V <sub>F(TO)</sub>	$T_J = T_J$ maximum		0.34	V
Forward slope resistance	r <sub>t</sub>			37.33	mΩ
Typical junction capacitance	C <sub>T</sub>	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		189	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	4.7	°C/W
Approximate weight			0.3	g
Approximate weight		0.01	OZ.	
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	Q04FN

#### Note

$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$

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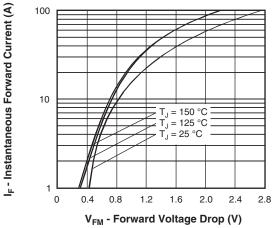


Fig. 1 - Maximum Forward Voltage Drop Characteristics

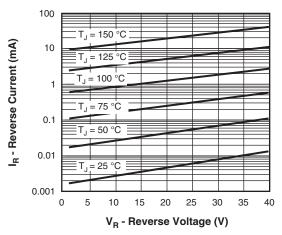


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

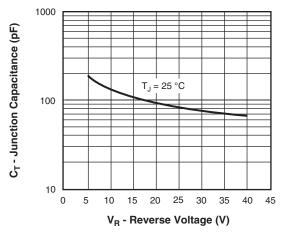


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

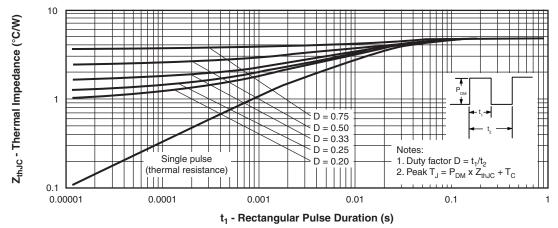


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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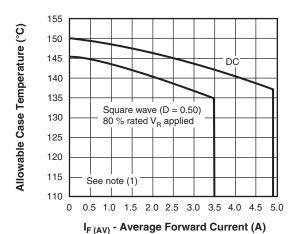
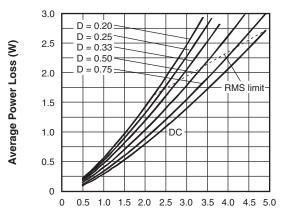


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



I<sub>F (AV)</sub> - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics

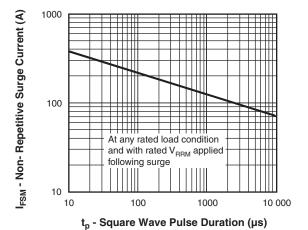


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

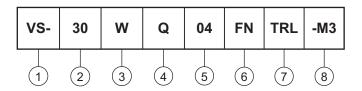
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = 80 \ \% \ \text{rated } V_R \end{aligned}$ 



### Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (3.5 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

- Voltage rating (04 = 40 V)

- FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30WQ04FN-M3	75	3000	Antistatic plastic tube		
VS-30WQ04FNTR-M3	2000	2000	13" diameter reel		
VS-30WQ04FNTRL-M3	3000	3000	13" diameter reel		
VS-30WQ04FNTRR-M3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95016</u>				
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95033			
SPICE model	www.vishay.com/doc?95288			
	www.vishay.com/doc?95630			



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